



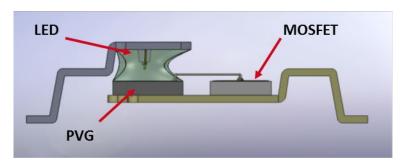
PHOTO-MOSFET SOLID STATE RELAYS OVERVIEW

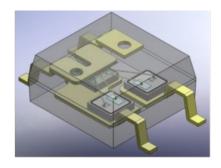
Introduction to Photo-MOSFET Solid State Relays

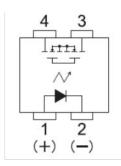
What is a Photo-MOSFET Solid State Relay?

Control Side: IR LED

Output Side: PVG & MOSFET output

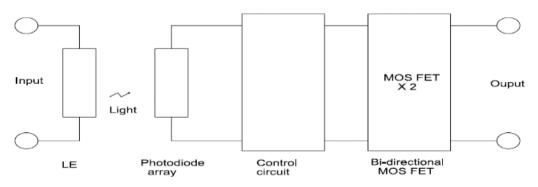






Functionality

- Current flow through IR LED generates IR frequency light
- ➤ IR incident on PVG, (photovoltaic generator), photo diode array creates photo current & generates voltage
- ➤ MOSFET Gate turns on when voltage exceeds threshold level





Features & General Specifications

AC or DC Switching in a very small package

- Output Voltage, V_L: 40 ~ 1500 V (DC or Peak AC)
- Output Current, I_L: 30mA ~ 4.5A
- ➤ Output Capacitance, C_{OUT}: 13 pF ~ 470 pF

Low operation current

➤ Input Current, I_F: 3 ~ 50 mA, 10 mA or higher recommended

Fast switching speed

 \triangleright Turn-On Time, T_{ON}: 0.05 mS ~ 3.0 mS

Stable On-resistance

➢ On Resistance R_{ON}: 0.07 ohm ~ 200 ohm

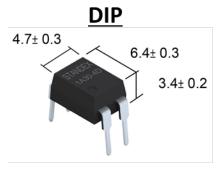
Extremely high Input-Output isolation

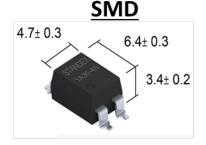
I/O Breakdown Voltage, V_{I/O}: SOP --1500 VAC; DIP & SMD -- 3750 / 5000 VAC

Low Off-state leakage current

Off State Leakage, ILEAK: 1uA ~ 10uA

- High Reliability and long operating life
- Vibration proof and shock proof
- **❖** No Contact Bounce
- ❖ Package : DIP / SMD / SOP
- ❖ Number of Pins: 4 / 6 / 8 pin





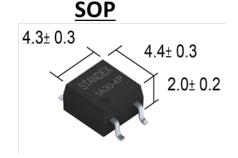




Photo-MOSFET Solid State Relay P/N System

Product Marking Special features – Nil = Standard, R = Reinforced Isolation or Q = AEC-Q101/Hi-Temp Packaging – <u>Tube or Reel</u> Package type – <u>DIP</u>, <u>SMD</u> or SO<u>P</u> Number of pins – 4, 6 or 8 Series number Contact form -A, B or C(1A + 1B)Number of poles – 1 or 2 Standex Meder Photo-MOSFET



Advantages of Photo-MOSFET Solid State Relays vs. Reed Relays

Advantage

Specification	Reed	Photo-MOSFET
Longer life expectancy	1 billion cycles at low level load	Nearly unlimited across rated loads
Fast switching speed		$\sqrt{}$
Smaller package		\checkmark
No bounce of contacts		\checkmark
Higher switching voltage	0 -10 kVDC	1 – 1.5 kVDC
Isolation voltage (across open output)	up to 15kVDC	No galvanic isolation
Isolation voltage (input to output)	up to 15kVDC	up to 5kVDC
Higher contact resistance	<150 mΩ	0.07 Ω ~ 200 Ω
Leakage current	~10 ⁻¹³	~10-6







Applications / Markets

















Measurement Equipment

(ex. Memory Testers, Logic Testers, Board Testers, Data Loggers, Multi-point Recorders, Flow meters, Timers)

❖ BMS

(ex. Battery monitoring, Battery Balancing, Isolation testing)

Telecommunication Equipment

(ex. Modems, Electronic switching systems, PBX, multi-function telephones, Fax)

Industrial Equipment

(ex. Robotics, Process Controllers, PLC, Compressors, Numerical Controllers, Thermostats, Relay output I/O boards, actuator drivers)

Medical Equipment

(ex. Electrocardiograph, Electroencephalograph, X-ray CT scanners)

Security Equipment

(ex. Home, Office & Building security systems)

Home Electronic Equipment

(ex. Air conditioners, Refrigerators, Microwave ovens, Washing machines, Internet TV, Home Network Box)

Telemetry Equipment

(ex. Automatic meter reading systems, Home medical equipment, Plant monitoring systems, Security systems)



Applications / Markets Cont'd

❖ Important Parameters When Considering an Application

➤ V₁ : Max. output load voltage

➢ I : Max. output load current

➤ R_{on} : On State Output Resistance

➤ C_{out} : On State Output Capacitance

➤ V_{I/O} : Isolation input to output (I/O Breakdown Voltage)

> T_{on} : for testing speed & efficiency

➤ I_{Leak} : Off State Leakage Current



PARTNER | SOLVE | DELIVER®

FOR MORE INFORMATION ON OUR CAPABILITIES,
AND HOW WE CAN PARTNER, SOLVE, AND DELIVER®
TO YOUR NEEDS, PLEASE VISIT US AT

STANDEXELECTRONICS.COM

